



# Precision Timing at High-Luminosity LHC with the CMS MIP Timing Detector

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# MIP Timing Detector (MTD) for CMS Phase-2 Upgrade



- Important to maintain detector performance during HL-LHC running
  - Time information will help to reduce pileup effects from approximately 200 simultaneous interactions
- MIP timing detector (MTD) consists of barrel timing layer (BTL) and endcap timing layer (ETL), providing 30-50 ps time resolution per track
  - BTL: LYSO crystal scintillator + SiPM readout
  - ETL: Silicon based sensor (LGAD) + ASIC readout
  - Two different detector technologies for radiation hardness and costs

### MTD Physics motivation: pile-up mitigation





- Important to maintain detector performance during HL-LHC running
  - Time information will help to reduce pileup effects from approximately 200 simultaneous interactions



The display of an event with a Higgs boson produced in the VBF process on top of 200 pile-up collisions.

### MTD Physics motivation: pile-up mitigation



- □ The mitigation of pile up effect improves all physics objects
- 4D vertexing (position+time) can remove
  - Spurious pileup tracks from "isolation cone" around leptons
  - Rejects spurious jets formed from pileup particles.

### **MTD Physics motivation: particle ID**



MTD can provide significant improvement for particle ID

• Heavy ion charm tag

Significant gains for searches for long-lived new particles

### 4D vertex reconstruction of primary and secondary vertices

Provides a close kinematic for Long Lived Particles decaying within MTD



# b-tagging performance with MTD

#### b-quark jets are important

- Primary decay mode of the Higgs, via  $H \rightarrow b \overline{b}$
- $^{\circ}$  Exclusive decay mode of the top quark, via  $t{\rightarrow}Wb$
- Significant improvement with MTD for b-quark identification efficiency
  - While reduced c-jet or light jets mistag rate



# Mip Timing Detector (MTD)



# **CMS MTD material budget using GEANT simulation**



- Largest contributions come from the BTL LYSO crystals (up to about 0.4 X<sub>o</sub>) accounting for about 90% of the total contribution in terms of radiation length in the barrel.
- □ The ETL adds just a small contribution in front of the endcap calorimeter, smaller than 0.2  $X_0$  and mostly due to the support aluminum plates.

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# MTD : Barrel Timing Layer (BTL)

- 3.8 cm thin cylindrical detector
  - $\circ\,$  located inside the tracker support tube,  $|\eta|<1.45$
  - $\circ$  ~5 m long, 38 m<sup>2</sup> surface





■ BTL construction: starting in early 2024!

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### **BTL sensors : LYSO crystal**

#### LYSO crystal bars (166k)

- Cerium-doped lutetium yttrium orthosilicate (LYSO:Ce) scintillation medium
- Well established in PET applications and vendors widely available
- High radiation tolerance
- $^{\circ}\ \tau_{rise}$  : ~100 ps,  $\tau_{decay}$  : ~ 40 ns
- $^\circ\,$  High Light Yield : 40000  $\gamma/MeV$



#### LYSO current status

- Single vendor selected
  - Considerably better offer
  - One of best vendor for performance-wise
  - Reliable vendor (large production capacity)
- Pre-production in progress
  - Ordered in March (2% of the total LYSO arrays)
  - QA/QC and construction database ready



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### **BTL sensors : SiPM**

#### SiPM (166k x 2 = 332k channel)

- Well consolidated technology
- Photon Detection Efficiency (PDE) : 20–40%
- Compact, robust, insensitive to magnetic fields
- Good radiation hardness
- Fast recovery time <10 ns</li>
- High dynamic range (10<sup>5</sup>)

#### SiPM current status

- $\circ\,$  Optimized cell size (25  $\mu m)$  as a default for BTL
  - Additional performance gain to boost signal
- SiPM die size (3.8×2.9 mm<sup>2</sup>) fixed to match with the thickest LYSO geometry

#### SiPM plans

- Tender starts in July
- Sign the production contract in September
- First batch delivered ~ Feb. 2024 (for 7 months)



### **BTL sensors : LYSO crystal and SiPM**



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**0**<sup>t</sup>

-10

40

30

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TEC

# **BTL Performance Optimization**

A dark count in the SiPM corresponds to a single cell firing due to a thermally generated electron.

#### □ The dark count rate (DCR)

- Proportional to the active area of the SiPM
  - Lowering V<sub>over voltage</sub> and optimizing S/N ratio
    ~ factor 2 less DCR
- Decreasing at lower temperatures by about a factor two every 7–10 °C
  - Further lowering SiPM's temperature to -45°C using Thermoelectric coolers (TEC)
    - ~ factor 2-3 less DCR
- Increasing with radiation damage
  - Annealing at room +65 °C during LHC shutdown and technical stops ~ factor 2 less DCR
  - Noise filtering with signal processing technique DLED in TOFHIR ~ factor 2 less DCR





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# The BTL prototyping phase is completed

□ Changing configuration of BTL with respect to the TDR (Almost same performance!)

- Smart thermal management with TECs (additional cooling and annealing)
- $\circ\,$  SiPM cell size choice : 25  $\mu m$  for boosting signal
- Thicker LYSO arrays for larger energy deposits
- TOFHIR2C optimization for electronic noise reductions



Ready for starting procurement and the production & assembly phase

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# MTD Endcap Timing Layer (ETL)

- Two double- sided disks for each side
  - Maximize geometrical acceptance (85% per disk)
  - $\circ$  Coverage : 1.6 <  $|\eta|$  < 3.0
  - Average of 1.8 hits per track
  - Time resolution per track < 35 ps
    - based on single hit resolution < 50 ps</li>
- Low-Gain Avalanche Diode (LGAD) sensor bump bonded readout ASIC (ETROC)

8000 modules (4 sensors each)

Disk 2

Disk 1



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# 2nd APCTP Workshop on EIC **ETL - Timing Resolution** Sensor CHANG-SEONG MOON (KNU) $\sigma_{\rm ioniz.} \sim 30 {\rm ps}$



### **ETL - Timing Resolution**

- $\square \sigma_{\textit{ionization}}$  : Random variation in particle energy deposition, determining the amplitude and the shape of the signal
  - $_{\circ}$  ~30 ps up to 1x10^{15}  $n_{eq}/cm^2,$  and ~40 ps up to 2x10^{15}  $n_{eq}/cm^2$
- $\Box \sigma_{jitter}$ : Mostly due to electronics noise and depends on the amplifier slew rate (dV/dt)
  - jitter <40 ps before irradiation.
  - No degrading in ETROC0 performance observed up to 100 Mrad
- $\square \ \sigma_{\ {\rm TDC}}$  : Effect of the TDC binning
- $\square \sigma_{\mathit{clock}}$  : Contribution from clock distribution

# Low Gain Avalanche Diode (LGAD) sensors

□ LGAD characteristics (16x16 pixel matrix, 1.3x1.3 mm<sup>2</sup> pixel size)

- Precision position reconstruction and timing resolution
- Highly improved radiation tolerance
- Moderate gain factor (10-30) to maximize S/N ratio -> Large signals with low noise
- $\circ\,$  Thin implanted gain layer of overall thickness of 35–50  $\mu m$
- Gain uniformity (>8 fC of charge)
- □ The additional Gain layer: highly boron-doped thin layer at the n-p junction
  - Generates the high field necessary to achieve charge multiplication.





### UFSD4 (FBK, Italy) wafers test in Korea



- The Red box represents the UFSD4 wafer #14 (W14), which has undergone wafer-level testing at KNU
- The Purple box represents three wafers which are shipped to CERN today for ETROC2 testing
- □ New 16 wafers (UFSD-K1), will be available for testing in a few weeks

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### **Probe station setup for wafer-level and sensor-level tests**



wafer tray

sensor tray

>There are 6 probe arms that use magnets to connect with the station (1 for signal read-out, 1 for bias voltage supplying, and 4 for grounding)

Two types of tray available for wafer-level and sensor-level tests

KCMS currently has plan to prepare a probe card and switching matrix for 16x16 sensors

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### Test setup for I-V measurements at KNU

➤KEITHLEY 2470 Sourcemeter

- Supply negative high voltage
- Reads the total current on bottom of the wafer

#### ► KEITHLEY 6487 Picoammeter

- Read the current of Device Under Test (DUT)



Guard ring - Ground Chassis ground **Grounding Wire** Pad - Current read  $\odot$ CATIINPUT Back plane - Bias voltage supply **KEITHLEY 6487** Wafer LO HI Triaxial BNC to Alligator 3x clips **V SOURCE** Picoammeter (Signal, Guard, Shield) OUTPUT

Dark box

#### I-V measurement of 1x1, 1x2, 2x2 sensors (FBK UFSD4 W14) at KNU



- V<sub>BD</sub> ~ 320 V in W14 and V<sub>BD</sub> ~ 250 V in W18
- The breakdown voltages do not depend on the sensor structures in the W14

#### I-V measurement of 2x2 sensors in wafer level (UFSD4 W14) at KNU



### I-V measurement of 5x5 sensor (UFSD4 W14) at KNU



#### Differences in wafer design and measurement

- Torino, UFSD4 wafer 8 is in the same Wafer Group Shallow | Gain Layer Dose: 0.98 | Carbon: 0.8 | Diffusion: CH-BL
- KNU, The wafer we have (W14) is in Wafer Group 8 Gain Layer Dose: 0.77 | Carbon: 0.6 | Diffusion: CL-BL Deep

#### ≻I-V parameters at KNU

- Main Diode: Signal read out -
- GR: Ground
- Near Pads: Ground
- BackSide: Connected HV
- Temperature: Room temp
- Compliance: 25 uA

#### **≻**I-V parameters 5x5 at Torino

- Main Diode: Signal read out
  - GR: Ground
  - BackSide: Connected HV \_
  - Compliance: 10 uA
  - Measured by Probe card

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### I-V measurement of 16x16 sensors (UFSD4 W14) in wafer level at KNU



### **Setup for C-V measurement at KNU**





### C-V measurement of the UFSD4 W14 1x1, 1x2, and 2x2 sensors at KNU



- □ Room temperature
- Depletion Voltage
  - Gain layer depletion Voltage ~ 44 V
  - Full depletion Voltage ~ 47 V

- Main Diode: HV
- GR: Connected HV
- BackSide: Ground
- Temperature: 10 °C
- Frequency: 1 KHz

### Gain layer uniformity studies with a column in 16x16 array at KNU



- □ Measurements performed on 16x16 T10\_GR5\_STD at KNU to extrapolate the uniformity of the gain layer
- C-V measurement are performed on 16 pads within one column
- Subsequent measurement will be conducted on pads near the center and pads within other reticles

### **Performance tests for LGAD sensors**

#### **Completed Market Survey for the procurement of the final LGADs Prototype.**

Qualified 4 vendors for production of the final LGAD sensors

#### □ Irradiated FBK sensors measured with a beta-source (Sr90) setup

- Collected charge and time resolution was satisfied with requirements
- Fully recover performance by increasing the bias voltage









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# MEMS.IOT.Sensor Bumping & Flip Chip Bonding

**Ball Stud Bump Bonding Process** 





# MEMS.IOT.Sensor Bumping & Flip Chip Bonding





### Bump-bonded dummy chip and sensor by the process (Option 1)



# Check points for the Gold Stud Bump-bonding

 Is Bump-bonding good for electrical contact?
 Whether Chip-2 bonding will be affected by the under-fill epoxy spilled from Chip-1 when bonding Chip-2 after bonding Chip-1?
 Will the under-fill liquid used for bonding spread to the wire Bonding Pad and become contaminated?

Check points 2 and 3 were problematic, because the device is too large.

As a result, after checking, check points 2 and 3 were OK



Interference between single chips : OK



Contamination of wire bonding pad : OK

# **Concept of electrical tests**

determine the number of bumps per serpentine by \_ measuring the resistance between wire bond pads



# **Electrical tests (Good Bumps)**

Slides from KU's presentation

Dummy Assemblies they are designed to study bump bonding performance and yeld



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# **Electrical tests (Bad Bumps)**

#### Slides from KU's presentation



# **Electrical tests on Bump-bonding sensors**

- Only pads capable of measuring resistance are selected and measured (16x16 bonded sensors (3 sets))
- Measurement method: (from R1 to R15)
  - 1st pad-2nd pad resistance measurement (R1)
  - 2nd pad-3rd pad resistance measurement (R2), in the same way, R3.....R15 measured.
  - Resistance measurements are made using a multi-meter.



**MEMSPACK** 

MEMS.IOT.Sensor



# **Electrical tests on Bump-bonding sensors**



**MEMSPACK** 

																		"bou	shorted nded"	a pads										
				Sam	ole let	t									S	ample	e righ	t									$\backslash$		/	
2	3 4	5	6	7 8	9	10 1	1 12	13	14 1	5 16	16	15 14	4 13	12	11 10	) 9	8	7 6	5	4 3	3 2	1							/	
R1 R2	R3 F	34																	R	4 R3	R2	R1	-					\/ <sub>"b</sub>	alcony	,11
Ω	R1	R2	R3	R4	R5	R6	R7	R8	R9	R10	R11	R12	R13	R14	R15	R15	R14	R13	R12	R11	R10	R9	R8	R7	R6	R5	R4	R3	R2	R1
S1	31.9	2.9	29.4	2.7	x	х	28.7	2.7	28.4	х	х	2.5	28.0	2.7	32.2	65.6	2.6	28.4	2.7	28.1	2.7	28.0	2.7	27.7	2.7	27.7	2.8	27.7	2.7	27.7
S2	28.6	2.7	91.4	2.7	x	x	91.1	2.5	154.4	x	x	2.4	91.3	2.5	69.4	58.3	2.4	27.4	2.4	27.5	2.5	27.4	2.6	27.5	2.7	27.6	2.8	27.7	2.8	27.7
S3	28.3	2.7	28.3	2.6	x	x	28.1	2.6	28.0	x	x	2.6	28.3	2.4	28.4	45.5	2.6	31.3	2.5	31.1	2.6	31.2	2.8	31.2	2.8	31.4	2.8	31.7	2.9	31.7

- Checked most uniform values measured in odd number (several tens ohm) and even number (several tens ohm).
- The "x" mark is a pad that cannot be measured, left sample identified in the same position.

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# **Distribution of resistances from bonding points**







Almost uniform distributions as expected : Maximum fluctuation 156  $\boldsymbol{\Omega}$ 

Plan to participate another bump-bonding tests with real LGAD and ETROC2 chip.

# Endcap Timing Layer ReadOut Chip (ETROC)



ETROC Block Diagram

- □ Total ETROC size: 16 X 16 pixel cell
  - One pixel cell size: 1.3mm X 1.3mm to match the LGAD sensor pixel size
- □ Targeting signal charge (1MIP): 6 20 fC
- TDC (time-to-digital converter) range
  - ~5 ns TOA (time of arrival)
  - ~10 ns TOT (time over threshold)

# **ETROC Development Plan**



- Analog front-end only
- Wire-bonded with LGAD sensor reached ~33 ps time resolution per hit with preamp. waveforms
- Passed 100 Mrad TID

- Added low-power TDC and 4x4 H-tree for clock distribution
- Bump-bonded with LGAD sensor reached ~42 ps time resolution per hit with TDC data

- First full-size chip (16x16) with all desired functionalities included
- All analog blocks silicon-proven; all digital blocks were verified in FPGA emulator

#### ETROC3 : Final chip

- The same functionalities as ETROC2, with improvements based on what will be learned from extensive ETROC2 testing
- Submission scheduled for 2024

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# **ETL Module design overview**

#### Module design overview



Basic scheme of a module

#### □ Module PCB

• Printed circuit board that serves as the power and readout interface for the module

#### □ 4x ETROC+LGAD subassembly

- 2x2 arrangement of bump-bonded assemblies
- Each of a 16x16 pixel LGAD sensor and an "ETROC" readout chip

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# **Assembling the ETL Modules**

The ETL detector will need ~8 thousand modules

Each module will be made of 4 LGAD sensors and ETROCs

□ An automated robotic gantry will be used for precision placement at the 10 micron level

All modules will then be assembled into disks at CERN





Wirebond and encapsulating



Apply film to baseplate, pick and place, and cure film

# **ETL Module assembly with Gantry**







- □ Aerotech 3+1 axis gantries were used for ETL module assembly.
- Based on a vacuum pump
  - Modules PCBs and sensors are securely fixed.
  - Vacuum arm is used for picking and moving sub-assembly.
- □ The robot arm rail is moved using magnetic force, enabling precise operations
- □ The camera measures and automatically corrects the position, rotation, and tilt of the sensors

# **Current Korea CMS Activities and Future plan**

KCMS responsible for the delivery of one layer of ETL sensors!

25% of the total endcap coverage

#### Significant contributions to prototyping towards production:

#### LGADs prototyping and validation:

- Detailed testing of prototype LGADs informed vendor qualification
- Probe station measurements to verify quality and uniformity of full-size wafers

#### ETROC2 testing

- Active in ETROC testing, including test beam campaigns for validation of the performance of the LGADs + ETROC chain
- Wafer processing:
  - Exploring wafer processing with one of the qualified LGADs vendors for wafer thinning, dicing, and surface preparation at Korean companies for the production phase
- Bump-bonding:
  - Exploring options with Korean companies for LGAD-to-ETROC bump-bonding during production





### **CERN-Korea CMS Sign-up Ceremony for the MTD project**

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CMS COLLABORATION CMS-2023-006

Memorandum of Understanding (MoU) for Korea-CMS contribution towards the MIP timing detector (MTD) for the Phase-2 CMS Upgrade

between The CMS Collaboration at CERN, hereafter referred to as CMS, on the one hand and The CMS Korea Institutes, hereinafter referred to as KCMS, on the other hand and hereinafter collectively referred to as Parties



#### Korea CMS group will contribute the LGAD production (25%), bump bonding process, front-end ASICs and module structures, etc.

Total budget: 2.2M CHF (equivalent to USD) supported by National Research Foundation of Korea (NRF)

### **Prototype next-generation LGAD sensor development**

#### **Prototype AC-LGAD Sensor**





• CMS plan to use 1.3x1.3  $mm^2$  pads

- $\circ~$  50-80  $\mu m$  inactive region between pads
- AC LGAD have been developed to solve fill factor problem
  - DC pad surrounding 17 AC strip
  - $\circ$  1.67 mm long with pitch of 100  $\mu m$
  - $\circ~50~\mu m$  thick substrate
- AC-LGAD can be used in future collider experiment
- AC-LGAD sensor test result was published in JINST
  - 2020 JINST 15 P09038

#### **Research result publication**

2020 JINST 15 P09038

Measurements of an AC-LGAD strip sensor with a 120 GeV proton beam

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ABSTRACT: The development of detectors that provide high resolution in four dimensions has attracted wide-spread interest in the scientific community for several applications in high-energy physics, nuclear physics, medical imaging, mass spectroscopy as well as quantum information. In addition to high time resolution and thanks to the AC-coupling of the electrodes, LGAD silicon sensors can provide high resolution in the measurement of spatial coordinates of an incident minimum ionizing particle. Such AC-coupled LGADs, also known as AC-LGADs, are therefore considered as candidates for future detectors to provide 4-dimensional measurements in a single sensing device with 100% fill factor. This article presents the first characterization of an AC-LGAD sensor with a proton beam of 120 GeV momentum at Fermilab. The sensor consists of strips with 80 µm width, fabricated at Brookhaven National Laboratory. The signal properties, efficiency, spatial, and time resolution are presented. The experimental results show that the time resolution of such an AC-LGAD is compatible to standard LGADs with similar gain, and that AC-LGADs can be segmented with fine pitches as standard strip or pixel detectors.

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### **AC-LGADs for Electron Ion Collider**

• AC-LGAD based Time of Flight (TOF) can provide the Particle ID for every particle in EIC.

- based on 30 ps timing resolution
- Ideally coarse pitch (500 μm, 1-2 cm strips) for sparse readout
- TOF can be used tracking layer (~20 μm resolution)



### **AC-LGADs for Electron Ion Collider**

#### AC-LGAD TOF Detectors for EIC – eRD112



#### **Barrel TOF**

Single layer with 30 ps resolution and 2%X<sub>0</sub> material budget per layer

#### Forward TOF Double layer with 25 ps resolution and 5%X<sub>0</sub> material budget per layer

#### **Backward TOF**

Double layer with 25 ps resolution and 5%X<sub>0</sub> material budget per layer

START Time 20 ps resolution Barrel TOF simulation (eta=0)



# ePIC: Tracking and Vertexing



30, 0.25

- ideal track points before/after PID detectors
- New Magnet with BABAR dimensions B = 1.7-2T

### **AC-LGAD Detectors for ePIC**

ePIC Barrel TOF ( $\sim 1\% X_0$ )



	Area (m <sup>2</sup> )	Channel size (mm <sup>2</sup> )	# of Channels	<b>Timing Resolution</b>	Spatial resolution	Material budget
Barrel TOF	10.9	0.5*10	2M	30 ps	30 $\mu m$ in $r \cdot \varphi$	0.01 X0
Forward TOF	2.22	0.5*0.5	6 M	25 ps	30 $\mu m$ in x and y	0.08 X0
B0 tracker	0.07	0.5*0.5	0.3M	30 ps	20 $\mu m$ in x and y	0.05 X0
RPs/OMD	0.14/0.08	0.5*0.5	0.6M/0.3M	30 ps	140 $\mu m$ in x and y	no strict req.

Requirements on timing and spatial resolutions and material budget are still being evaluated and are subject to change as the design matures, and we will continue to explore common designs for these detectors where possible to reduce cost and risk.

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# Summary

# The CMS MIP Timing Detector will measure precision timing of charged particles produced inside CMS.

- Provides significant pileup mitigation, furthering the experiment's mission in the HL-LHC era.
- Brings new capabilities to CMS that could help to search new phenomena in the HL-LHC.

#### **BTL will be instrumented with LYSO crystals + SiPMs, read-out by the TOFHIR**

- Beginning of life performance (30-40 ps) within requirements
- End-of-life performance (~ 60 ps) close to requirements
- The BTL prototyping phase is completed and now entering production phase

#### **ETL will be instrumented with LGADs read out by the ETROC**

- Performance at beginning and end of life within requirements (single hit resolution < 50 ps)
- $\circ\,$  LGAD market survey done  $\rightarrow$  Will enter a tender process soon.
- Full-scale 16x16 ETROC2 arrived and Initial system test with bare ETROC2 in progress.

# Common MTD DAQ system is being developed together for the ETL and BTL. Mechanical engineering of the full detector system is preparing.